

#### **TVS Diode**

unit : mm

#### Features

- Transient protection for data lines to IEC61000-4-2(ESD) 15KV(air), 8KV(contact)
- Small package for use in portable electronics
- Low operating and clamping voltage

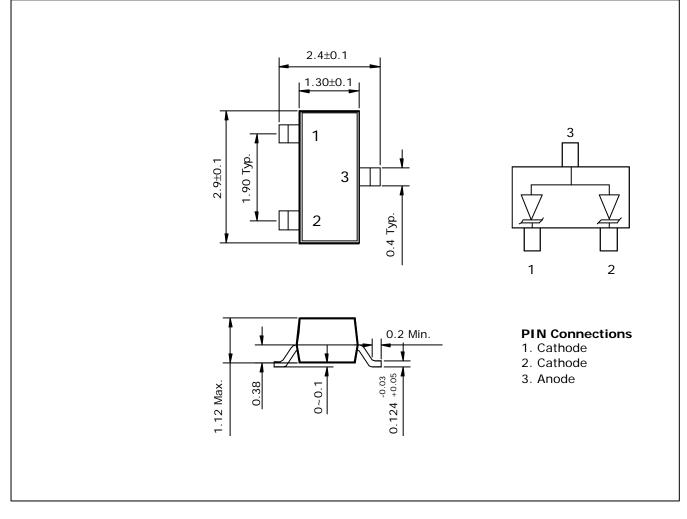
#### Applications

- Cellular Handsets and Accessories
- Microprocessor based equipment
- Notebooks, Desktops and Servers

#### **Ordering Information**

Type NO.	Marking	Package Code	
SDT05S	S05	SOT-23	

### **Outline Dimensions**



# SDT05S

# Absolute maximum ratings

Absolute maximum ratings			<b>Ta=25°</b> C	
Characteristic	Symbol	Ratings	Unit	
Peak pulse power ( tp = $8/20 \ \mu s$ )	P <sub>PK</sub>	200	W	
Peak pulse current (tp = $8/20 \ \mu s$ )	l <sub>pp</sub>	12	А	
Lead soldering temperature	TL	260 (10sec.)	°C	
Operating temperature	TJ	-55 ~ 125	°C	
Storage temperature	T <sub>stg</sub>	-55 ~ 150	°C	

## **Electrical Characteristics**

Ta=25°C

				1a=25 C			
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Reverse stand-off voltage	V <sub>RWM</sub>				5	V	
Reverse breakdown voltage	V <sub>BR</sub>	I <sub>t</sub> =1mA	6			V	
Reverse leakage current	I <sub>R</sub>	$V_{RWM} = 5V$ , $T = 25$			20	μA	
Clamping voltage	V <sub>c</sub>	I <sub>pp</sub> =1A, tp=8/20 μs			9.8	V	
Junction capacitance	C」	Pin 1 to 2 V <sub>R</sub> =0V, f=1MHz			100	pF	
Junction capacitance	C」	Pin 1 to 3 and Pin 2 to 3 $V_R=0V$ , f=1MHz			150	рF	

### **Electrical Characteristics Curves**

Fig. 1 Power derating curve

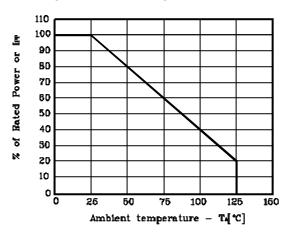


Fig. 3 Pulse Waveform

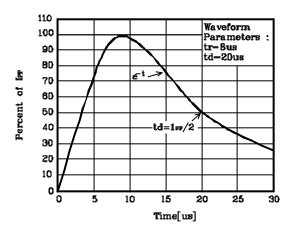


Fig. 2 None-repetitive peak pulse power vs pulse time

SDT05S

